

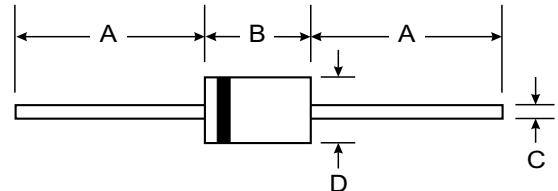
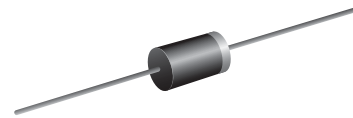
**VOLTAGE RANGE: 600 - 1000V**  
**CURRENT: 3.0 A**

### Features

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

### Mechanical Data

- Case: DO-201AD, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 1.2 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



DO-201AD		
Dim	Min	Max
A	25.40	—
B	7.20	9.50
C	1.20	1.30
D	4.80	5.30
All Dimensions in mm		

### Maximum Ratings and Electrical Characteristics T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	BYT13-600	BYT13-800	BYT13-1000	Unit
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>	600	800	1000	V
Working Peak Reverse Voltage	V <sub>RWM</sub>				
DC Blocking Voltage	V <sub>R</sub>				
RMS Reverse Voltage	V <sub>R(RMS)</sub>	420	560	700	V
Average Rectified Output Current (Note 1) @ T <sub>A</sub> = 55°C	I <sub>O</sub>	3.0			A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	150			A
Forward Voltage @ I <sub>F</sub> = 3.0A	V <sub>FM</sub>	1.3			V
Peak Reverse Current @ T <sub>A</sub> = 25°C At Rated DC Blocking Voltage @ T <sub>A</sub> = 100°C	I <sub>RM</sub>	10.0 100			μA
Reverse Recovery Time (Note 2)	t <sub>rr</sub>	50		75	nS
Typical Junction Capacitance (Note 3)	C <sub>j</sub>	80		50	pF
Operating Temperature Range	T <sub>j</sub>	-65 to +125			°C
Storage Temperature Range	T <sub>STG</sub>	-65 to +150			°C

- Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case  
 2. Measured with I<sub>F</sub> = 0.5A, I<sub>R</sub> = 1.0A, I<sub>RR</sub> = 0.25A. See figure 5.  
 3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.